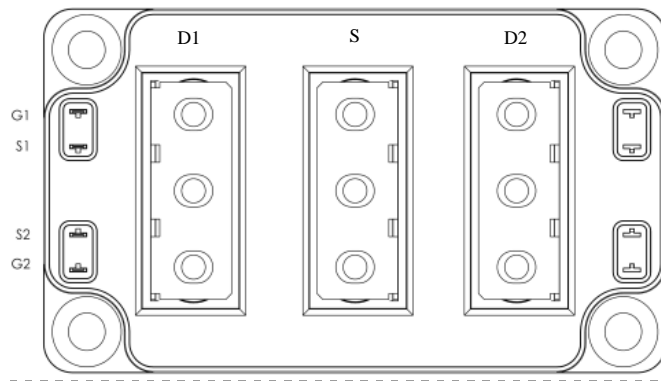
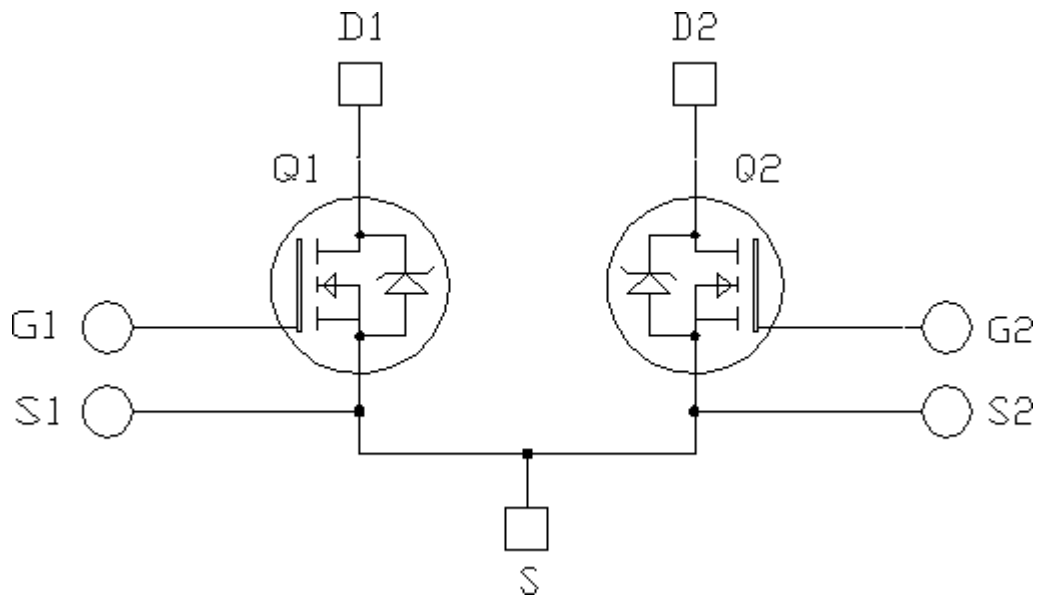


Dual Common Source SiC MOSFET Power Module

Product Overview

The MSCSM70DUM017AG device is a 700V/1021A dual common source silicon carbide (SiC) MOSFET power module.



All ratings at $T_j = 25\text{ }^\circ\text{C}$, unless otherwise specified.



These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCSM70DUM017AG device:

- SiC Power MOSFET
 - Low $R_{DS(on)}$
 - High temperature performance
- Kelvin source for easy drive
- Low stray inductance
- High level of integration
- Aluminum Nitride (AlN) substrate for improved thermal performance
- M5 power connectors

Benefits

The following are the benefits of MSCSM70DUM017AG device:

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- Low profile
- RoHS compliant

Application

The following are the applications of MSCSM70DUM017AG device:

- AC switches
- Switched mode power supplies
- Uninterruptible power supplies

1. Electrical Specifications

This section provides the electrical specifications of the MSCSM70DUM017AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings of MSCSM70DUM017AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Maximum Ratings	Unit
V_{DSS}	Drain-Source voltage	700	V
I_D	Continuous drain current	$T_C = 25\text{ }^\circ\text{C}$	1021
		$T_C = 80\text{ }^\circ\text{C}$	812
I_{DM}	Pulsed drain current	2000	
V_{GSmax}	Gate-Source voltage	-10/25	V
$R_{DS(on)}$	Drain-Source ON resistance	2.1	m Ω
P_D	Power dissipation	$T_C = 25\text{ }^\circ\text{C}$	2750

The following table lists the electrical characteristics of MSCSM70DUM017AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
I_{DSS}	Zero gate voltage drain current	$V_{GS} = 0V$ $V_{DS} = 700V$	—	—	450	μA
$R_{DS(on)}$	Drain-Source on resistance	$V_{GS} = 20V$ $I_D = 360A$	$T_J = 25\text{ }^\circ\text{C}$	—	1.7	2.1
			$T_J = 175\text{ }^\circ\text{C}$	—	2.1	—
$V_{GS(th)}$	Gate threshold voltage	$V_{GS} = V_{DS}$ $I_D = 36\text{ mA}$	1.9	2.4	—	V
I_{GSS}	Gate-Source leakage current	$V_{GS} = 20V$ $V_{DS} = 0V$	—	—	900	nA

MSCSM70DUM017AG

Electrical Specifications

The following table lists the dynamic characteristics of MSCSM70DUM017AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
C _{iss}	Input capacitance	V _{GS} = 0V	—	40.5	—	nF
C _{oss}	Output capacitance	V _{DS} = 700V	—	4.6	—	
C _{rss}	Reverse transfer capacitance	f = 1 MHz	—	0.26	—	
Q _g	Total gate charge	V _{GS} = -5V/20V	—	1935	—	nC
Q _{gs}	Gate-Source charge	V _{Bus} = 470V	—	522	—	
Q _{gd}	Gate-Drain charge	I _D = 360A	—	315	—	
T _{d(on)}	Turn-on delay time	V _{GS} = -5V/20V	—	78	—	ns
T _r	Rise time	V _{Bus} = 400V		125		
T _{d(off)}	Turn-off delay time	I _D = 720A		214		
T _f	Fall time	R _{Gon} = 3.1Ω R _{Goff} = 1.8Ω		92		
E _{on}	Turn-on energy	V _{GS} = -5V/20V	—	10.9	—	mJ
E _{off}	Turn-off energy	V _{Bus} = 400V I _D = 720A R _{Gon} = 3.1Ω R _{Goff} = 1.8Ω	—	15.8	—	
R _{Gint}	Internal gate resistance		—	0.63	—	Ω
R _{thJC}	Junction-to-case thermal resistance		—	—	0.055	°C/W

The following table lists the body diode ratings and characteristics of MSCSM70DUM017AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min.	Typ.	Max.	Unit
V _{SD}	Diode forward voltage	V _{GS} = 0V I _{SD} = 360A	—	3.4	—	V
		V _{GS} = -5V I _{SD} = 360A	—	3.8	—	
t _{rr}	Reverse recovery time	I _{SD} = 360A	—	38	—	ns
Q _{rr}	Reverse recovery charge	V _{GS} = -5V	—	2862	—	nC
I _{rr}	Reverse recovery current	V _R = 400V di _F /dt = 10000A/μs	—	133	—	A

1.2 Thermal and Package Characteristics

The following table lists the thermal and package characteristics of the MSCSM70DUM017AG device.

Table 1-5. Thermal and Package Characteristics

Symbol	Characteristic	Min.	Max.	Unit		
V _{ISOL}	RMS isolation voltage, any terminal to case t = 1 min, 50 Hz/60 Hz	4000	—	V		
T _J	Operating junction temperature range	-40	175	°C		
T _{JOP}	Recommended junction temperature under switching conditions	-40	T _{Jmax} -25			
T _{STG}	Storage case temperature	-40	125			
T _C	Operating case temperature	-40	125			
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package weight	—	320	g		

1.3 Typical SiC MOSFET Performance Curve (Per SiC MOSFET)

This section shows the typical SiC MOSFET performance curves of the MSCSM70DUM017AG device.

Figure 1-1. Junction-to-Heatsink Thermal Impedance

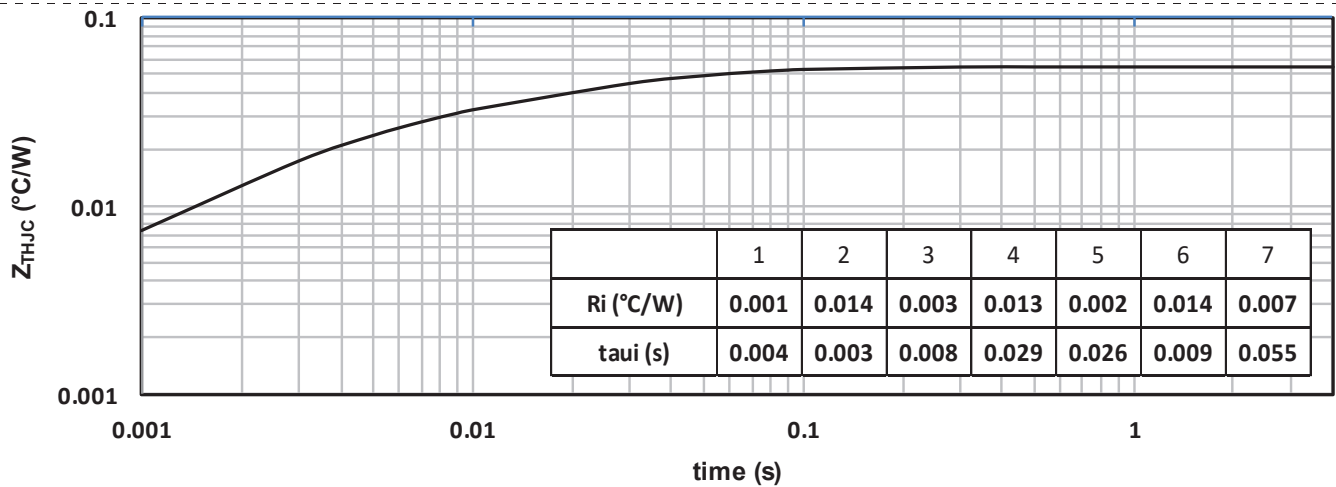


Figure 1-2. Output Characteristics, $T_J = 25\text{ }^\circ\text{C}$

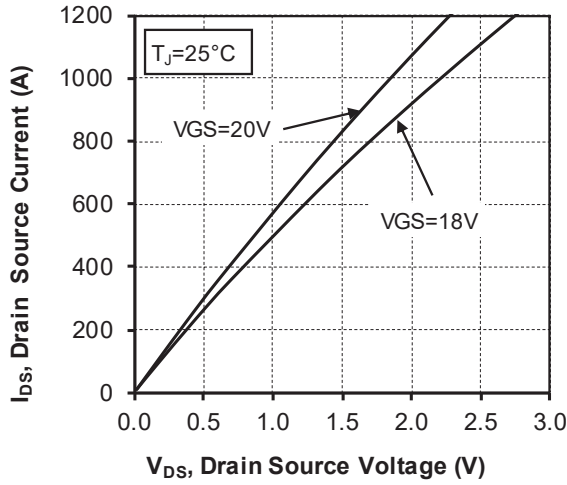


Figure 1-3. Output Characteristics, $T_J = 175\text{ }^\circ\text{C}$

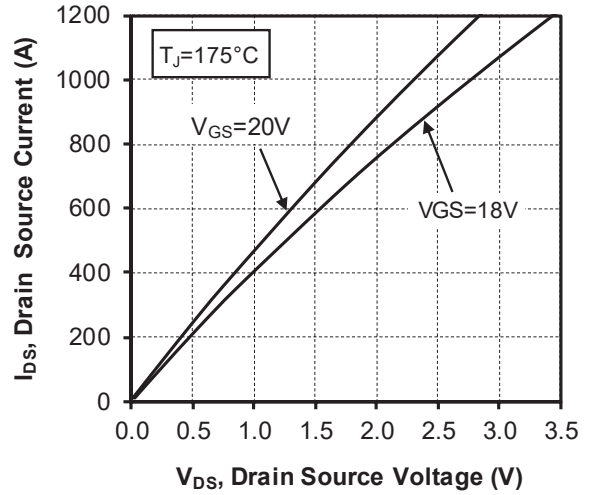


Figure 1-4. Normalized $R_{DS(on)}$ vs. Temperature

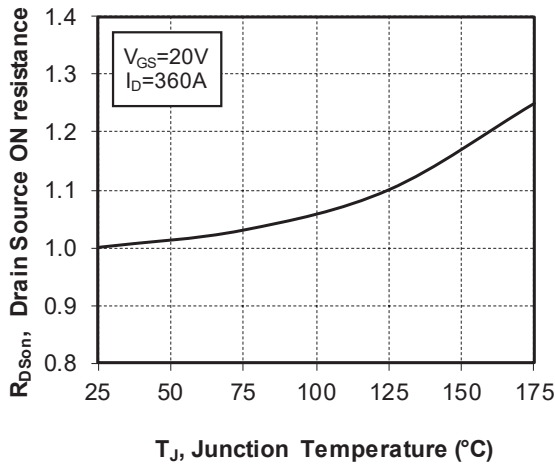


Figure 1-5. Transfer Characteristics

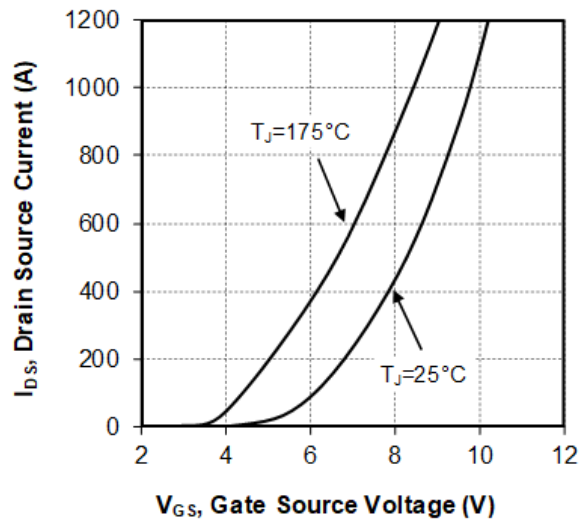


Figure 1-6. Capacitance vs. Drain Source Voltage

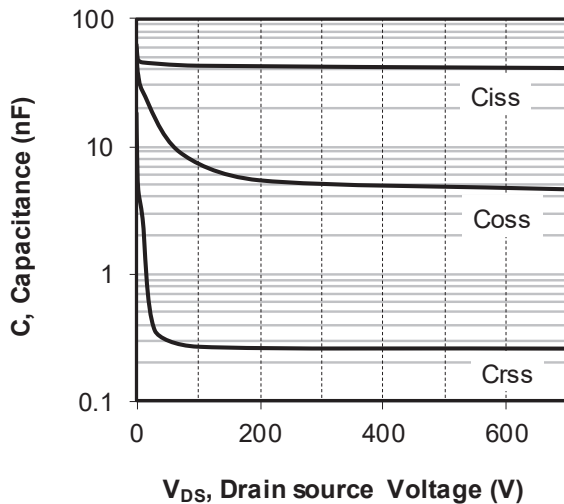


Figure 1-7. Gate Charge vs. Gate Source Voltage

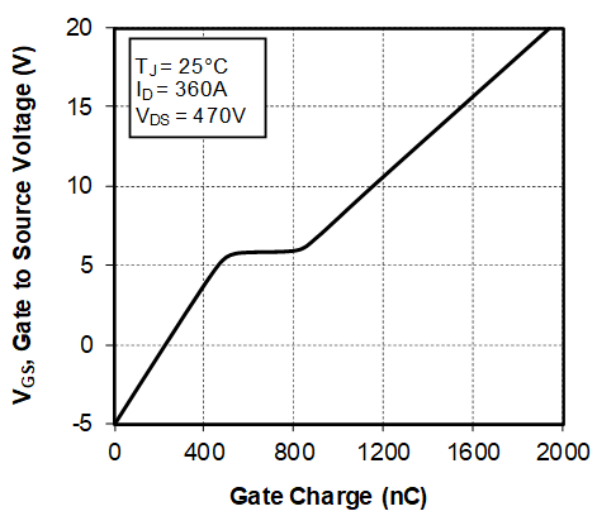


Figure 1-8. Body Diode Characteristics, $T_J = 25^\circ\text{C}$

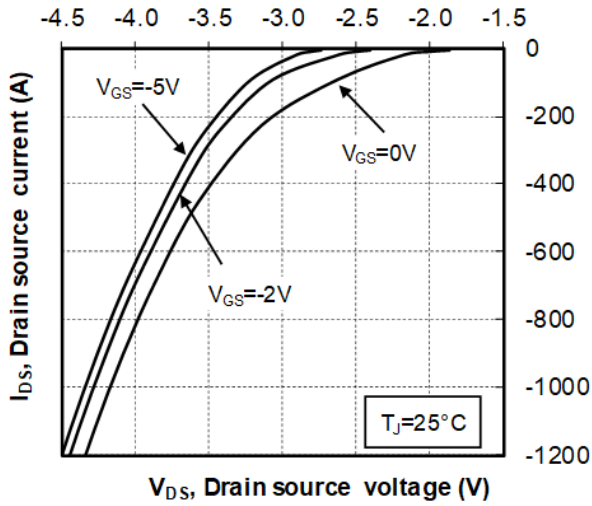


Figure 1-9. 3rd Quadrant Characteristics, $T_J = 25^\circ\text{C}$

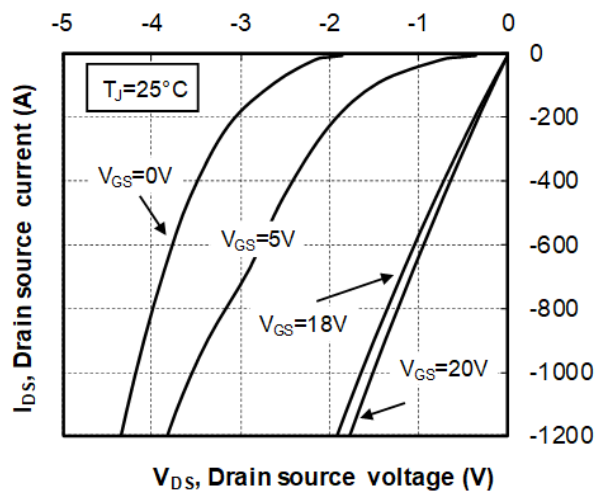


Figure 1-10. Body Diode Characteristics, $T_J = 175^\circ\text{C}$

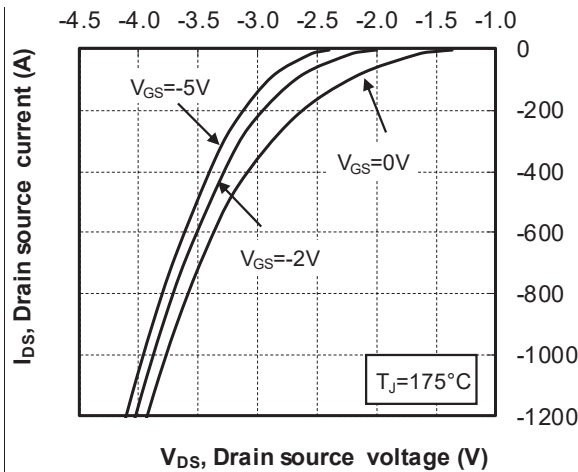


Figure 1-11. 3rd Quadrant Characteristics, $T_J = 175^\circ\text{C}$

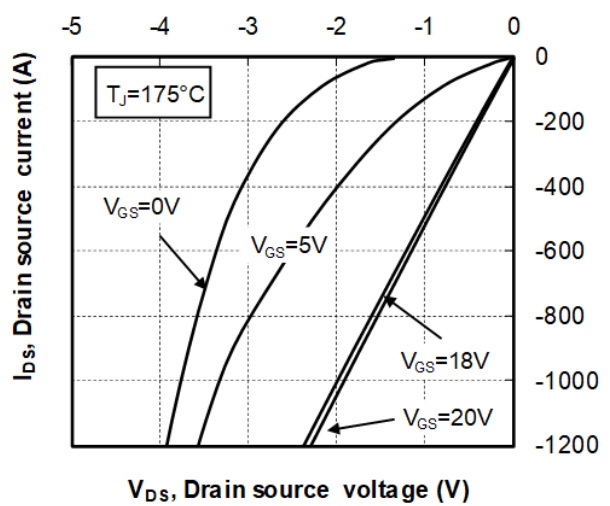


Figure 1-12. Turn On Energy vs. R_g

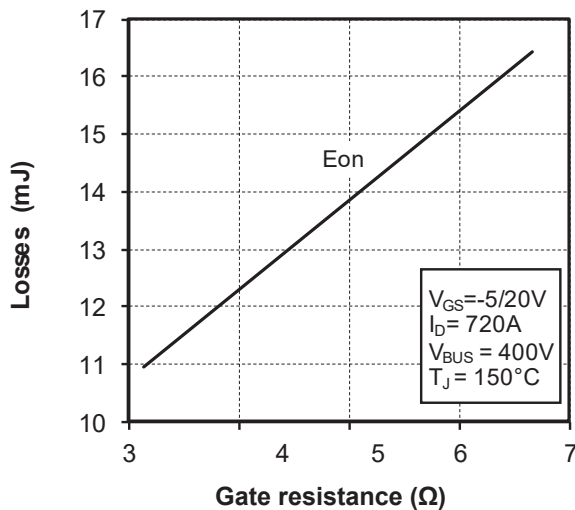


Figure 1-13. Turn Off Energy vs. R_g

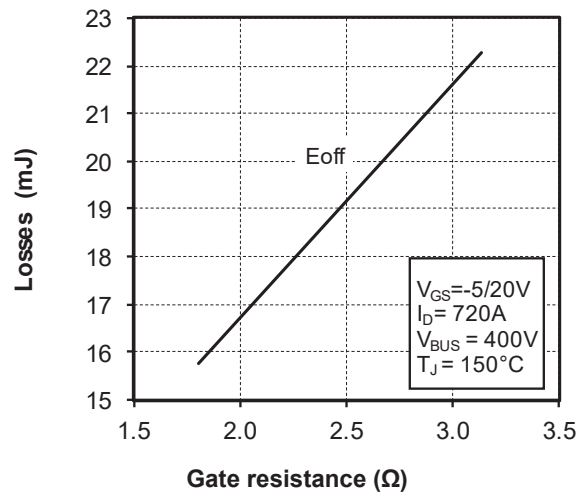


Figure 1-14. Switching Energy vs. Current

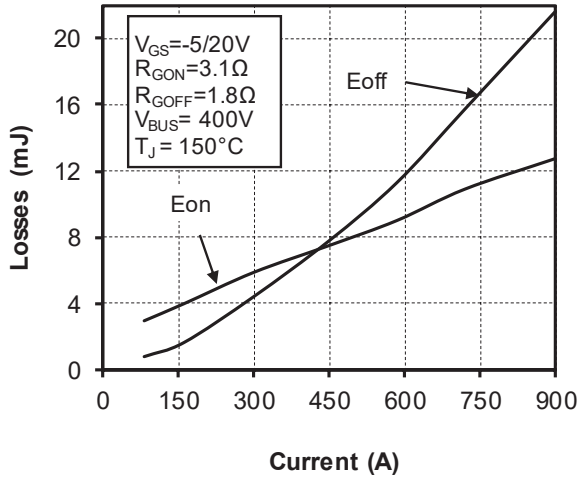
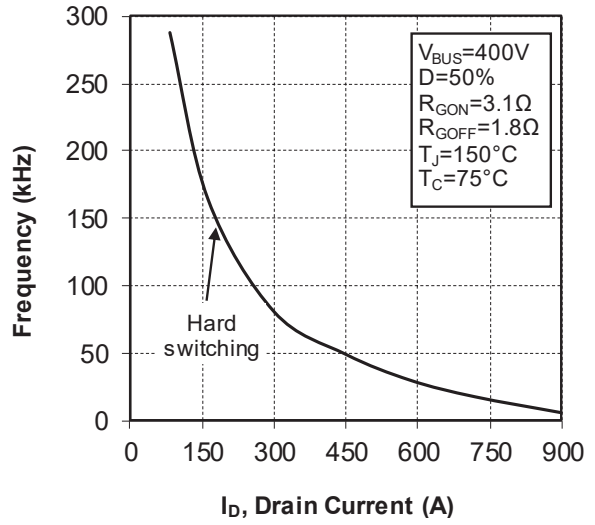


Figure 1-15. Operating Frequency vs. Drain Current



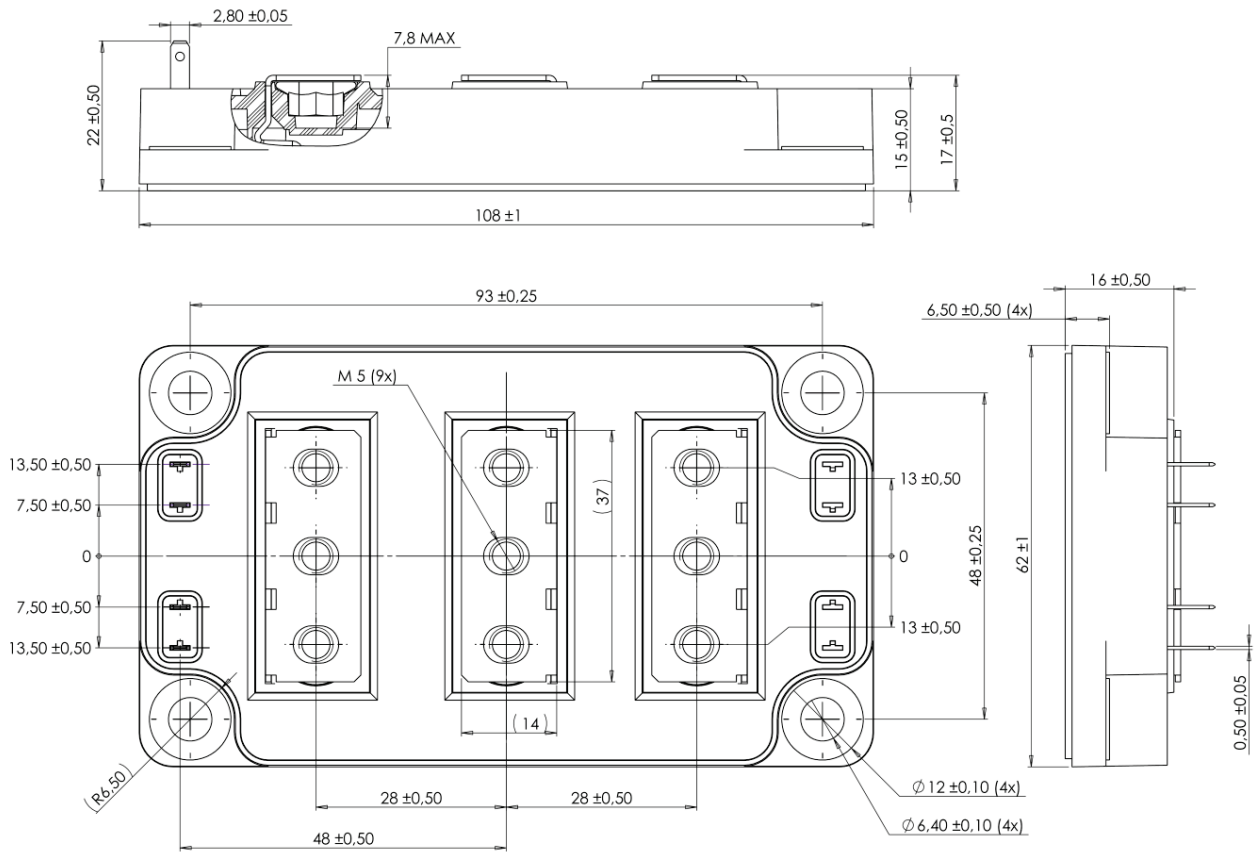
2. Package Specifications

The following section shows the package specification of the device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM70DUM017AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



3. Revision History

Revision	Date	Description
A	12/2021	Initial Revision.

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